NSN 5961-01-083-8870



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-083-8870 **Inclosure Material:** Ceramic or glass or metal **Overall Length:** Between 0.250 inches and 0.328 inches **Terminal Length:** Between 0.312 inches and 0.500 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Terminal Circle Diameter:** Between 0.038 inches and 0.043 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to base voltage/static/emitter open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Test Data Document:** 81349-mil-s-19500/509 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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No